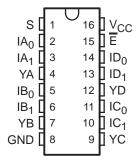
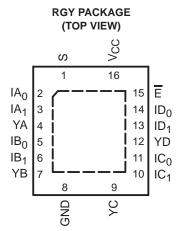
- Wide Bandwidth (BW = 350 MHz Min)
- Low Differential Crosstalk (X_{TALK} = -68 dB Typ)
- Low Power Consumption (I_{CC} = 10 μA Max)
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on} = 5 Ω Typ)
- Rail-to-Rail Switching on Data I/O Ports (0 to V_{CC})
- V_{CC} Operating Range From 3 V to 3.6 V
- I_{off} Supports Partial-Power-Down Mode Operation

- Data and Control Inputs Have Undershoot Clamp Diodes
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Suitable for Both 10 Base-T/100 Base-T Signaling







description/ordering information

The TI TS3L100 LAN switch is a 4-bit 1-of-2 multiplexer/demultiplexer with a single switch-enable (\overline{E}) input. When \overline{E} is low, the switch is enabled and the I port is connected to the Y port. When \overline{E} is high, the switch is disabled and the high-impedance state exists between the I and Y ports. The select (S) input controls the data path of the multiplexer/demultiplexer.

ORDERING INFORMATION

TA	PACKAG	et .	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Tape and reel	TS3L100RGYR	TK100
	0010 B	Tube TS3L100D		
	SOIC - D	Tape and reel	TS3L100DR	TS3L100
0°C to 70°C	SSOP (QSOP) – DBQ	Tape and reel	TS3L100DBQR	TK100
	TOOOD DW	Tube	TS3L100PW	TI(400
	TSSOP – PW	Tape and reel	TS3L100PWR	TK100
	TVSOP - DGV	Tape and reel	TS3L100DGVR	TK100

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A - MAY 2004 - REVISED OCTOBER 2004

description/ordering information (continued)

This device can be used to replace mechanical relays in LAN applications. This device has low r_{on} , wide bandwidth, and low differential crosstalk, making it suitable for 10 Base-T, 100 Base-T, and various other LAN applications.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{E} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE

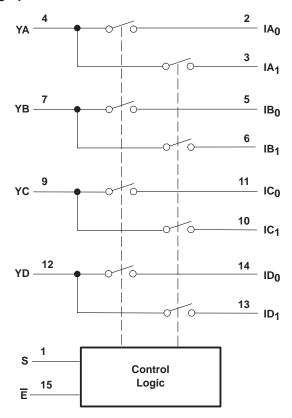
INP	UTS	INPUT/OUTPUT	FUNCTION				
Ē S		ΥX	FUNCTION				
L	L	IX ₀	$YX = IX_0$				
L	Н	IX ₁	$YX = IX_1$				
Н	X	Z	Disconnect				

PIN DESCRIPTIONS

PIN NAME	DESCRIPTION
IAn–IDn	Data I/Os
S	Select input
Ē	Enable input
YA-YD	Data I/Os



logic diagram (positive logic)



TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A - MAY 2004 - REVISED OCTOBER 2004

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}		–0.5 V to 4.6 V
Control input voltage range, V _{IN} (see Notes 1 a	and 2)	–0.5 V to 4.6 V
Switch I/O voltage range, V _{I/O} (see Notes 1, 2,	, and 3)	–0.5 V to 4.6 V
Control input clamp current, I _{IK} (V _{IN} < 0)		–50 mA
I/O port clamp current, $I_{I/OK}$ ($V_{I/O} < 0$)		–50 mA
ON-state switch current, I _{I/O} (see Note 4)		±128 mA
Continuous current through V _{CC} or GND termi	nals	±100 mA
Package thermal impedance, θ _{JA} (see Note 5)	: D package	73°C/W
	DB package	82°C/W
	DBQ package	90°C/W
	PW package	108°C/W
Storage temperature range, T _{sto}		–65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground, unless otherwise specified.
 - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - 3. V_I and V_O are used to denote specific conditions for V_{I/O}.
 - 4. II and IO are used to denote specific conditions for II/O.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions (see Note 6)

		MIN	MAX	UNIT
VCC	Supply voltage	3	3.6	V
V_{IH}	High-level control input voltage (\overline{E},S)	2	VCC	V
V _{IL}	Low-level control input voltage $(\overline{\overline{E}}, S)$	0	0.8	V
TA	Operating free-air temperature	0	70	°C

NOTE 6: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



TS3L100 QUAD SPDT WIDE-BANDWIDTH LAN SWITCH WITH LOW ON-STATE RESISTANCE

SCDS161A - MAY 2004 - REVISED OCTOBER 2004

electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V $_{\pm}$ 0.3 V (unless otherwise noted)

PARA	METER		TEST CONDI	ITIONS	MIN	TYP [†]	MAX	UNIT
VIK	Ē, S	$V_{CC} = 3 V$,	$I_{IN} = -18 \text{ mA}$				-1.8	V
V _{hys}	Ē, S					150		mV
ΙΗ	Ē, S	$V_{CC} = 3.6 \text{ V},$	VIN = VCC				±1	μΑ
I _I L	Ē, S	$V_{CC} = 3.6 \text{ V},$	V _{IN} = GND				±1	μΑ
loz‡		V _{CC} = 3.6 V,	$V_O = 0 \text{ to } 3.6 \text{ V},$ $V_I = 0,$	Switch OFF			±1	μА
los§		V _{CC} = 3.6 V,	$V_O = 0 \text{ to } 0.5 V_{CC},$ $V_I = 0,$	Switch ON	50			mA
l _{off}		$V_{CC} = 0$,	$V_0 = 0 \text{ to } 3.6 \text{ V},$	V _I = 0			15	μΑ
ICC		$V_{CC} = 3.6 \text{ V},$	$I_{I/O} = 0,$	Switch ON or OFF		0.1	10	μΑ
∆ICC	E, S	$V_{CC} = 3.6 \text{ V},$	One input at V _{CC} – 0.6 V,	Other inputs at V _{CC} or GND			750	μΑ
ICCD		V _{CC} = 3.6 V,	I and Y ports open,	V _{IN} input switching 50% duty cycle			0.45	mA/ MHz
C _{IN}	Ē, S	f = 1 MHz				3		pF
0	I port	\\. 0	f = 1 MHz,	Cuitab OFF	5			
COFF	Y port	$V_I = 0$,	Outputs open,	Switch OFF		10		pF
CON	•	V _I = 0,	f = 1 MHz, Outputs open,	Switch ON		17		pF
		$V_{I} = 0 \text{ V}, \qquad I_{O} = 48 \text{ mA}$		I _O = 48 mA		5	7	0
r _{on}	ACC = 3 A		$V_{I} = 2 \text{ V},$ $I_{O} = 15 \text{ mA}$			10	15	Ω
Δr _{on}	$V_{I} = 3 V$, Switch ON, $I_{O} = 15 \text{ mA}$			1		Ω		

 $V_{\mbox{\scriptsize I}},\,V_{\mbox{\scriptsize O}},\,I_{\mbox{\scriptsize I}},$ and $I_{\mbox{\scriptsize O}}$ refer to I/O pins. $V_{\mbox{\scriptsize IN}}$ refers to the control inputs.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V, R_L = 100 Ω , C_L = 35 pF (unless otherwise noted) (see Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	UNIT
tON	S	Y	1	7.5	ns
tOFF	S	Y	1	3.5	ns

[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}\text{C}$.

dynamic characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS									
X _{TALK} (Diff)	$R_L = 100 \Omega$,	f = 10 MHz, see Figure 8,	$t_r = t_f = 2 \text{ ns}$	-55	dB						
X _{TALK}	$R_L = 100 \Omega$,	f = 30 MHz, see Figure 6		-68	dB						
O _{IRR}	$R_L = 100 \Omega$,	f = 30 MHz, see Figure 7		-42	dB						
BW	$R_L = 100 \Omega$, see Fig	gure 5		350	MHz						

[†] All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_A = 25°C.

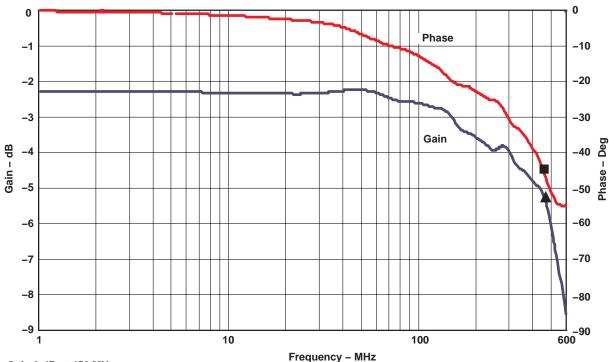


[†] All typical values are at $V_{CC} = 3.3 \text{ V}$ (unless otherwise noted), $T_A = 25^{\circ}C$.

For I/O ports, the parameter I_{OZ} includes the input leakage current.

[§] The IOS test is applicable to only one ON channel at a time. The duration of this test is less than one second.

OPERATING CHARACTERISTICS

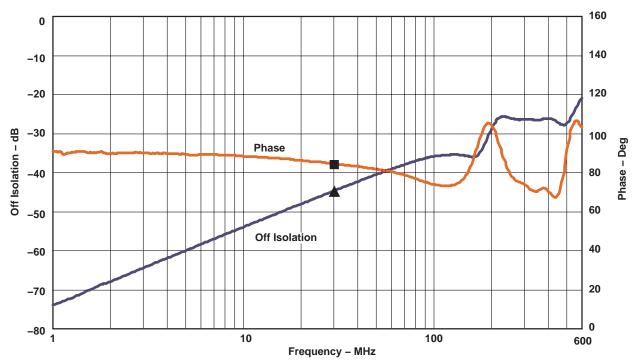


- Gain 3 dB at 450 MHz
- Phase at 3-dB Frequency, -43 Degrees

Figure 1. Gain/Phase vs Frequency



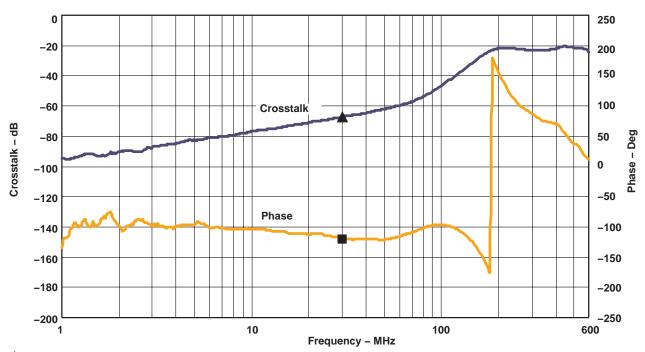
OPERATING CHARACTERISTICS



- Off Isolation at 30 MHz, -44.6 dB
- Phase at 30 MHz, 84.41 Degrees

Figure 2. Off Isolation vs Frequency

OPERATING CHARACTERISTICS

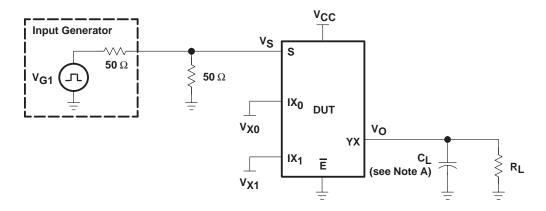


- ▲ Crosstalk at 30 MHz, −67.3 dB
- Phase at 30 MHz, -118.4 Degrees

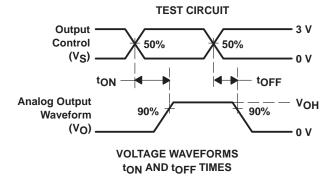
Figure 3. Crosstalk vs Frequency



PARAMETER MEASUREMENT INFORMATION



TEST	VCC	RL	CL	V _{X0}	V _{X1}
ton	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND
tOFF	3.3 V ± 0.3 V	100 Ω	35 pF	GND	3 V
	3.3 V ± 0.3 V	100 Ω	35 pF	3 V	GND



NOTES: A. C_L includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_{O} = 50 \Omega$, $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- C. The outputs are measured one at a time, with one transition per measurement.

Figure 4. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

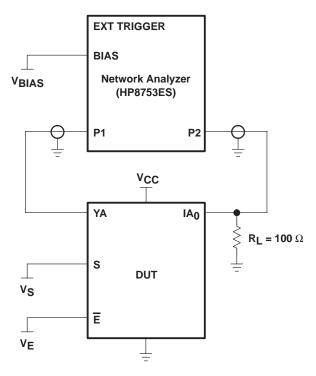


Figure 5. Test Circuit for Frequency Response (BW)

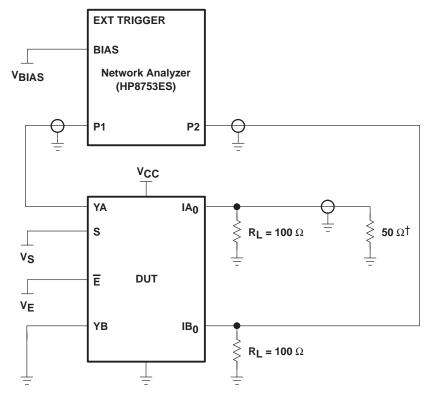
Frequency response is measured at the output of the ON channel. For example, when $V_S = 0$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog I/O ports are left open.

HP8753ES setup

Average = 4 RBW = 3 kHz V_{BIAS} = 0.35 V ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 \dagger A 50- $\!\Omega$ termination resistor is needed for the network analyzer.

Figure 6. Test Circuit for Crosstalk (X_{TALK})

Crosstalk is measured at the output of the nonadjacent ON channel. For example, when $V_S=0$, $V_E=0$, and YA is the input, the output is measured at IB_0 . All unused analog input (Y) ports are connected to GND and output (I) ports are connected to GND through $50-\Omega$ pulldown resistors.

HP8753ES setup

Average = 4

RBW = 3 kHz

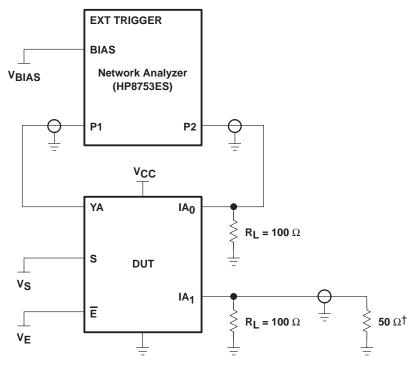
 $V_{BIAS} = 0.35 V$

ST = 2 s

P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION



 $[\]dagger$ A 50-Ω termination resistor is needed for the network analyzer.

Figure 7. Test Circuit for Off Isolation (OIRR)

OFF isolation is measured at the output of the OFF channel. For example, when $V_S = V_{CC}$, $V_E = 0$, and YA is the input, the output is measured at IA₀. All unused analog input (Y) ports are left open and output (I) ports are connected to GND through $50-\Omega$ pulldown resistors.

HP8753ES setup

Average = 4 RBW = 3 kHz $V_{BIAS} = 0.35 V$ ST = 2 s P1 = 0 dBM



PARAMETER MEASUREMENT INFORMATION

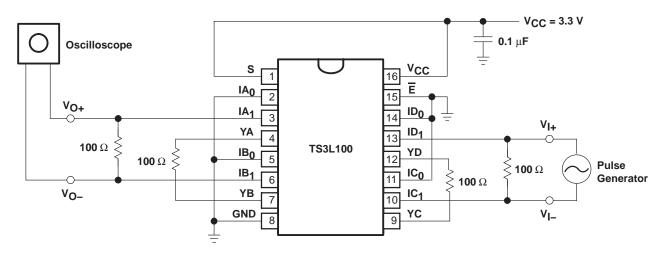


Figure 8. Differential Crosstalk Measurement

Differential crosstalk is a measure of coupling noise between a transmit and receive pair in the LAN application. Differential crosstalk depends on the edge rate, frequency, and load. This is calculated from the equation, $X_{TALK}(Diff)$ db = 20 log $V_{O}(Diff)/V_{I}(Diff)$, where $V_{O}(Diff)$ is the differential output voltage and $V_{I}(Diff)$ is the differential input voltage.





10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TS3L100DBQR	ACTIVE	SSOP	DBQ	16	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100	Samples
TS3L100DGVR	ACTIVE	TVSOP	DGV	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100	Samples
TS3L100DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TS3L100	Samples
TS3L100PW	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100	Samples
TS3L100PWG4	ACTIVE	TSSOP	PW	16	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100	Samples
TS3L100PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100	Samples
TS3L100PWRG4	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TK100	Samples
TS3L100RGYR	ACTIVE	VQFN	RGY	16	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	0 to 70	TK100	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

10-Dec-2020

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE MATERIALS INFORMATION

www.ti.com 18-Nov-2020

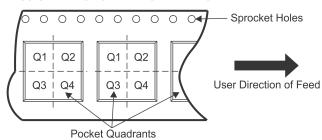
TAPE AND REEL INFORMATION





Γ	Α0	Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
	K0	Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
Г	P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

"All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS3L100DBQR	SSOP	DBQ	16	2500	330.0	12.5	6.4	5.2	2.1	8.0	12.0	Q1
TS3L100DGVR	TVSOP	DGV	16	2000	330.0	12.4	6.8	4.0	1.6	8.0	12.0	Q1
TS3L100DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TS3L100PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TS3L100RGYR	VQFN	RGY	16	3000	330.0	12.4	3.8	4.3	1.5	8.0	12.0	Q1

www.ti.com 18-Nov-2020



*All dimensions are nominal

7. di di neriolo di e nomina							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS3L100DBQR	SSOP	DBQ	16	2500	333.2	345.9	28.6
TS3L100DGVR	TVSOP	DGV	16	2000	853.0	449.0	35.0
TS3L100DR	SOIC	D	16	2500	333.2	345.9	28.6
TS3L100PWR	TSSOP	PW	16	2000	853.0	449.0	35.0
TS3L100RGYR	VQFN	RGY	16	3000	853.0	449.0	35.0

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



SHRINK SMALL-OUTLINE PACKAGE



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 inch, per side.
- 4. This dimension does not include interlead flash.5. Reference JEDEC registration MO-137, variation AB.



SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SHRINK SMALL-OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

4206353-3/P 03/14

NOTE: All linear dimensions are in millimeters



RGY (R-PVQFN-N16)

PLASTIC QUAD FLATPACK NO-LEAD



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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